V20DL45BP

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TMBS[®] (Trench MOS Barrier Schottky) Rectifier for PV Solar Cell Bypass Protection

Ultra Low $V_F = 0.31$ V at $I_F = 5$ A





DESIGN SUPPORT TOOLS AVAILABLE



PRIMARY CHARACTERISTICS				
I _{F(AV)}	20 A			
V _{RRM}	45 V			
I _{FSM}	160 A			
V _F at I _F = 20 A (T _A = 125 °C)	0.50 V			
T _{OP} max. (AC model)	150 °C			
T_J max. (DC forward current)	200 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Single			

FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

MECHANICAL DATA

Case: SMPD (TO-263AC) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	V20DL45BP	UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	45	V		
Maximum DC forward current (fig. 1)	I _{F(DC)} ⁽¹⁾	20	А		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	160	А		
Operating junction temperature range (AC model)	T _{OP}	-40 to +150	°C		
Junction temperature in DC forward current without reverse bias, t = \leq 1 h $$	T _J ⁽²⁾	≤ 200	°C		

Note

(1) With heatsink

⁽²⁾ Meets the requirements of IEC 61215 ed.2 bypass diode thermal test

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ROHS COMPLIANT

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ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 5 A	T _A = 25 °C	- V _F (1)	0.42	-	V
	I _F = 10 A			0.48	-	
	I _F = 20 A			0.55	0.64	
	I _F = 5 A	T _A = 125 °C		0.31	-	
	I _F = 10 A			0.38	-	
	I _F = 20 A			0.50	0.58	
Reverse current	V _B = 45 V	T _A = 25 °C	– I _R ⁽²⁾	-	2.5	mA
	V _R = 45 V	T _A = 125 °C	'R (-)	20	50	ШA

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 5 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER SYMBOL		V20DL45BP	UNIT	
Typical thermal resistance	$R_{\theta JC}$	1.6	°C/W	
	R _{0JA} (1)(2)	45	C/ W	

Notes

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

⁽²⁾ Free air, without heatsink

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE BASE QUANTITY		DELIVERY MODE
SMPD (TO-263AC)	V20DL45BP-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

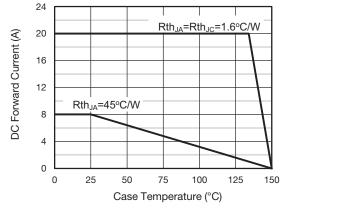


Fig. 1 - Forward Current Derating Curve

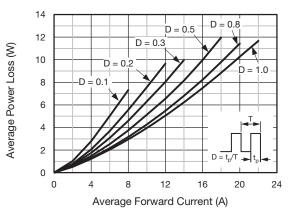


Fig. 2 - Forward Power Loss Characteristics

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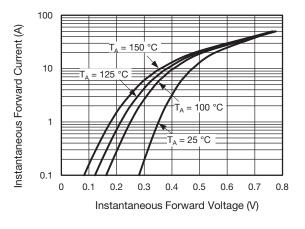


Fig. 3 - Typical Instantaneous Forward Characteristics

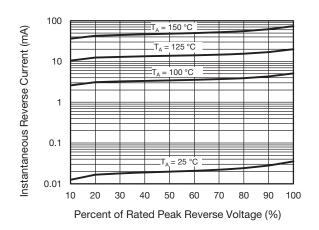


Fig. 4 - Typical Reverse Characteristics

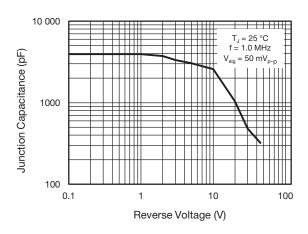


Fig. 5 - Typical Junction Capacitance

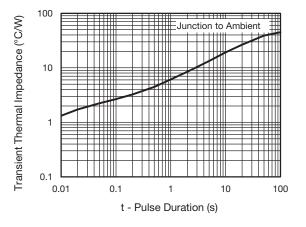


Fig. 6 - Typical Transient Thermal Impedance

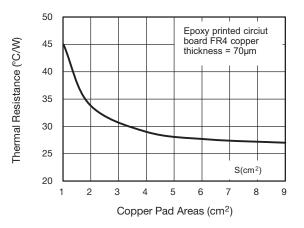


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

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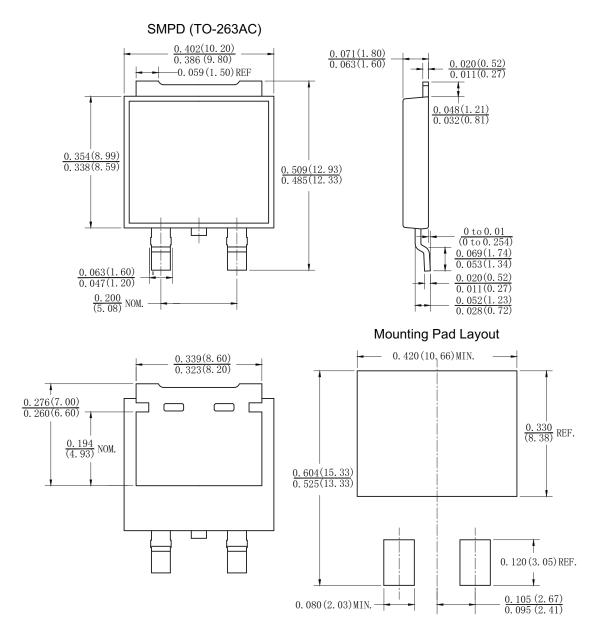
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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